

## CALCULATION OF THE CRYSTAL FIELD PARAMETERS FOR $\text{Eu}^{3+}$ DOPED IN $\text{SrAl}_2\text{O}_4$ AND $\text{SrIn}_2\text{O}_4$ SPINELS

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### Abstract

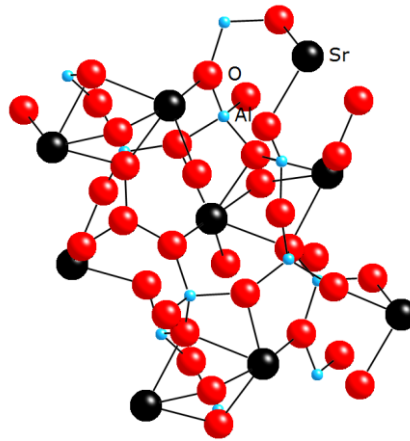
Strontium aluminate ( $\text{SrAl}_2\text{O}_4$ ) and the indium aluminate ( $\text{SrIn}_2\text{O}_4$ ) spinels have been proven to be efficient host materials, which offer the possibility of generating broadband emission after doping with rare earth trivalent ions. The present work is devoted to the calculation of the crystal field parameters and the energy levels of the trivalent europium doped in  $\text{SrAl}_2\text{O}_4$  and  $\text{SrIn}_2\text{O}_4$  spinels, using the superposition model of the crystal field. Using the intrinsic parameters for  $\text{Eu}^{3+}$ - $\text{O}^{2-}$  bonds, and the geometry structure of the each crystal, we modeled the  $\text{CFP}_s$  and simulated the low-lying energy levels schemes. The obtained results are compared with the experimental data and discussed.

## 1. Introduction

Strontium aluminate ( $\text{SrAl}_2\text{O}_4$ ) has been proven to be efficient host material with a wide band gap, which offers the possibility of generating broadband emission [1]. The spinel  $\text{SrAl}_2\text{O}_4$  has a two phase, where the phase  $\alpha$  is monoclinic structure at low temperature, with space group  $\text{P}_{21}$ , with unit cell parameters  $a = 8.447 \text{ \AA}$ ,  $b = 8.816 \text{ \AA}$ ,  $c = 5.163 \text{ \AA}$ ,  $\beta = 93.42^\circ$  and the  $\beta$  phase, a pseudo-hexagonal structure predominated at higher temperatures [2, 3].

The A site in the  $\text{Sr}^{2+}$  structure has tetrahedral coordination, with radius equal to  $1.12 \text{ \AA}$ , so their crystallographic positions are too large for  $\text{Eu}^{3+}$  ions which have the radius equal to  $0.95 \text{ \AA}$ , while the B site in  $\text{Al}^{3+}$  structure has distorted octahedral coordination. In this case, the  $\text{Eu}^{3+}$  ions will substitute the  $\text{Al}^{3+}$  ions which have the radius equal to  $0.54 \text{ \AA}$ , without charge compensation [4], in the octahedral site and a new complex  $[\text{EuO}_6]^{9-}$  is created.

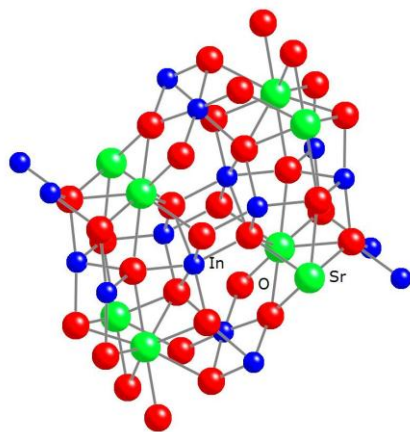
The structure of the strontium aluminate spinel  $\text{SrAl}_2\text{O}_4$  is presented in the figure 1 [5].



**Figure 1.** The structure of  $\text{SrAl}_2\text{O}_4$  [5]. Drawn with VESTA [6]

The structure of the indium aluminate ( $\text{SrIn}_2\text{O}_4$ ) spinel belongs to the orthorhombic  $P_{\text{nam}}$  (62) ( $D_{2h}^{16}$ ), with eight formula units per cell. The constants lattice for  $\text{SrIn}_2\text{O}_4$  spinel undoped is:  $a = 9.83\text{\AA}$ ,  $b = 11.5\text{\AA}$ ,  $c = 3.27\text{\AA}$  [7] and the local symmetry of the  $\text{Eu}^{3+}$  in  $\text{SrIn}_2\text{O}_4$  spinel is  $C_s = \{E, \sigma_h\}$ . The A site in the  $\text{Sr}^{2+}$  structure has tetrahedral coordination, while the B site in  $\text{In}^{3+}$  structure has distorted octahedral coordination. In this case, the  $\text{Eu}^{3+}$  ions will substitute the  $\text{In}^{3+}$  ions which have the radius equal to  $0.79\text{\AA}$  in the octahedral site and a new complex  $[\text{EuO}_6]^{9-}$  is created.

The structure of the strontium aluminate spinel  $\text{SrAl}_2\text{O}_4$  is presented in the figure 2 [8].



**Figure 2.** The structure of  $\text{SrIn}_2\text{O}_4$  spinel [8]. Drawn with VESTA [6]

The present work is devoted to the modelation of the crystal field parameters of the  $\text{Eu}^{3+}$  doped in the  $\text{SrAl}_2\text{O}_4$  and  $\text{SrIn}_2\text{O}_4$  spinels in the superposition model of the crystal field and simulation the low-lying energy levels of the trivalent europium doped in  $\text{SrAl}_2\text{O}_4$  and

SrIn<sub>2</sub>O<sub>4</sub> spinels, by diagonalization the Hamiltonian of the systems. The obtained results are compared with experimental data and discussed [9-11].

## 2. Modeling of the crystal field parameters

The crystal field created by the ligands of the host matrices SrAl<sub>2</sub>O<sub>4</sub> and SrIn<sub>2</sub>O<sub>4</sub> spinels type split the energy levels of the impurity ion Eu<sup>3+</sup>.

In order to describe the energy levels of the ground state of rare-earth ions doped in crystals, we use the Hamiltonian [12]:

$$H = \sum B_k^q O_k^q \quad (1)$$

where:

$B_k^q$  - are the crystal field parameters (CFP) associated with the extended Stevens operators  $O_k^q$ .

Using the superposition model will be calculated the crystal field parameters. In this model the crystal field parameters may be expressed as [13-15]:

$$B_k^q = \sum_L \bar{B}_k(R_L) K_k^q(\theta_L, \phi_L) \quad (2)$$

where:

$K_k^q$  - are the coordination factors [13-15] defined in terms of the angles  $\theta_L$  and  $\phi_L$  of the L - ligand positions.

They  $\bar{B}_k(R_L)$  are the intrinsic parameters and they are given by [13-15]:

$$\bar{B}_k(R_L) = \bar{B}_k(R_0) \left( \frac{R_0}{R_L} \right)^{t_k} \quad (3)$$

Here they  $\bar{B}_k(R_0)$  are the intrinsic crystal field parameters corresponding to  $R_0$  reference distance;  $R_L$  is the distance from impurity ion to ligand L and  $R_0$  represents the reference distance;  $t_k$  are the power law exponents that are adjustable semi-empirical parameters [13-15].

The intrinsic crystal field parameters  $\bar{B}_k(R_0)$  can be transferred from similar cluster [EuO<sub>6</sub>]<sup>9-</sup> [13].  $R_L$  can be approximate as [16]:

$$R_L \approx R_h + \frac{1}{2}(r_L - r_h) \quad (4)$$

where:  $R_h$  - is the distance between Sr<sup>2+</sup>, Al<sup>3+</sup>, In<sup>3+</sup> and ligands.

Using the geometry of the host matrices [2, 3], the values of the intrinsic parameters  $\bar{B}_k(R_0)$  for  $\text{Eu}^{3+} - \text{O}^{2-}$  can be transferred from [17-19].

For the adjustable parameters  $t_k$  we taken the values  $t_2 = 5$ ,  $t_4 = 9$  and  $t_6 = 13$ , given by the point charge model of crystal field theory. Thus, the crystal field parameters  $B_k^q$  from (1) are calculated, using the Esq. ((2)-(3)).

### 3. Results and discussion

In the Table 1 are given the reference distance ( $R_0$ ) and crystal field intrinsic parameters for  $\text{Eu}^{3+} - \text{O}^{2-}$  at reference distance for the  $\text{Eu}^{3+}$  ion for both spinels.

**Table 1.** The intrinsic parameters

<b><math>\text{Eu}^{3+} - \text{O}^{2-} (\text{SrIn}_2\text{O}_4)</math></b>				
$R(\text{\AA})$	$R_0(\text{\AA})$	$\bar{B}_2(\text{cm}^{-1})$	$\bar{B}_4(\text{cm}^{-1})$	$\bar{B}_6(\text{cm}^{-1})$
	[17]	[17-19]	[17-19]	[17-19]
2.17	2.98	370	35	21
<b><math>\text{Eu}^{3+} - \text{O}^{2-} (\text{SrAl}_2\text{O}_4)</math></b>				
$R(\text{\AA})$	$R_0(\text{\AA})$	$\bar{B}_2(\text{cm}^{-1})$	$\bar{B}_4(\text{cm}^{-1})$	$\bar{B}_6(\text{cm}^{-1})$
	[17]	[17-19]	[17-19]	[17-19]
2.52	2.98	370	35	21

In the Table 2 are given the crystal field parameters of  $\text{Eu}^{3+}$  doped in  $\text{SrAl}_2\text{O}_4$  and  $\text{SrIn}_2\text{O}_4$  spinels, calculated in the superposition model.

**Table 2.** The crystal field parameters

<b>Parameter</b>	<b>Superposition Model (<math>\text{Eu}^{3+} : \text{SrAl}_2\text{O}_4</math>)</b>	<b>Superposition Model (<math>\text{Eu}^{3+} : \text{SrIn}_2\text{O}_4</math>)</b>
$B_2^0$	244	1938
$B_2^1$	764	550
$B_2^2$	450	-1869
$B_4^0$	53	-4
$B_4^1$	116	-73

Parameter	Superposition Model (Eu <sup>3+</sup> : SrAl <sub>2</sub> O <sub>4</sub> )	Superposition Model (Eu <sup>3+</sup> : SrIn <sub>2</sub> O <sub>4</sub> )
$B_4^2$	55	-1173
$B_4^3$	182	-353
$B_4^4$	63	-4567
$B_6^0$	16	-1761
$B_6^1$	14	-1504
$B_6^2$	-117	-5270
$B_6^3$	-70	105
$B_6^4$	-13	-1054
$B_6^5$	-300	-223
$B_6^6$	36	8634

With these parameters and the parameters of the free Eu<sup>3+</sup> ions [20] we have diagonalized the Hamiltonian of the title system with SPECTRA, a computer program. The low-lying energy levels for this ion are presented in the Table 3.

**Table 3.** The energy levels of the Eu<sup>3+</sup> doped in SrIn<sub>2</sub>O<sub>4</sub> and SrAl<sub>2</sub>O<sub>4</sub> spinels

Energy levels	Experimental [21-23]	Calculate (this work) (Eu <sup>3+</sup> : SrIn <sub>2</sub> O <sub>4</sub> )	Calculate (this work) (Eu <sup>3+</sup> : SrAl <sub>2</sub> O <sub>4</sub> )
${}^7F_0$	0	0	0
${}^7F_1$	381	408	500
${}^7F_2$	988	1729	1085
${}^7F_3$	1987	2079	1940
${}^7F_4$	3076	3085	3030
${}^7F_5$	-	4108	3990
${}^7F_6$	-	5162	5345
${}^5D_0$	17182	17964	19207

Energy levels	Experimental [21-23]	Calculate (this work) (Eu <sup>3+</sup> : SrIn <sub>2</sub> O <sub>4</sub> )	Calculate (this work) (Eu <sup>3+</sup> : SrAl <sub>2</sub> O <sub>4</sub> )
<sup>5</sup> D <sub>1</sub>	-	20217	20163
<sup>5</sup> D <sub>2</sub>	21322	21523	21668
<sup>5</sup> D <sub>3</sub>	-	24482	24585
<sup>5</sup> L <sub>6</sub>	25316	25541	25850

It can see from these tables that the calculated values are close with experimental one [23, 24] which confirm the validity of the superposition model of crystal field for this case.

Also, we have given the position of energy levels <sup>7</sup>F<sub>5</sub>, <sup>7</sup>F<sub>6</sub>, <sup>5</sup>D<sub>1</sub>, <sup>5</sup>D<sub>3</sub>, for systems Eu<sup>3+</sup>: SrIn<sub>2</sub>O<sub>4</sub> and Eu<sup>3+</sup>: SrAl<sub>2</sub>O<sub>4</sub>, which had not yet observed experimentally.

## Conclusions

In the present paper has been performed the crystal field calculation parameters and the low-lying energy levels for Eu<sup>3+</sup> doped in the SrIn<sub>2</sub>O<sub>4</sub> and SrAl<sub>2</sub>O<sub>4</sub> spinels.

The crystal field parameters of Eu<sup>3+</sup> doped in SrAl<sub>2</sub>O<sub>4</sub> and SrIn<sub>2</sub>O<sub>4</sub> spinels have been calculated in the frame of the superposition model of the crystal field.

The low-lying energy level schemes of the europium ions in the studied host, has been calculated by diagonalizing the Hamiltonian of the system.

Reasonable agreement between the calculated and measured crystal field splittings confirms validity of the results obtained in this paper.

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